
E40M

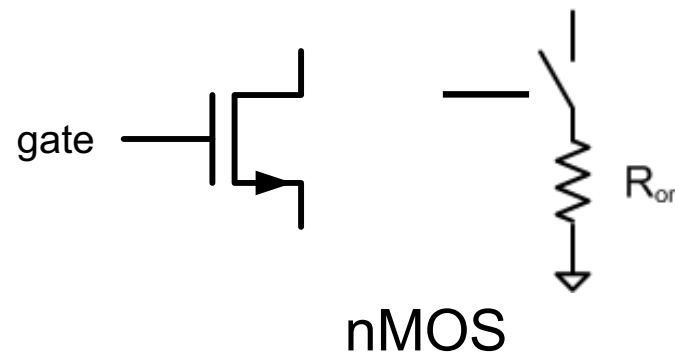
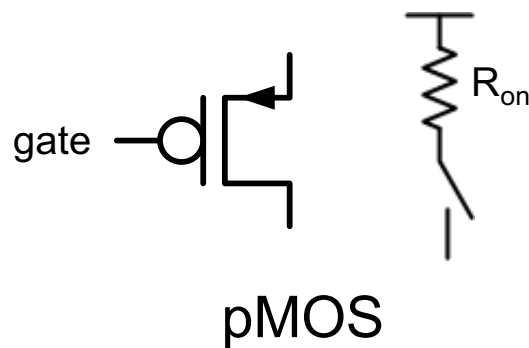
MOS Transistors, CMOS Logic Circuits,
and Cheap, Powerful Computers

Reading

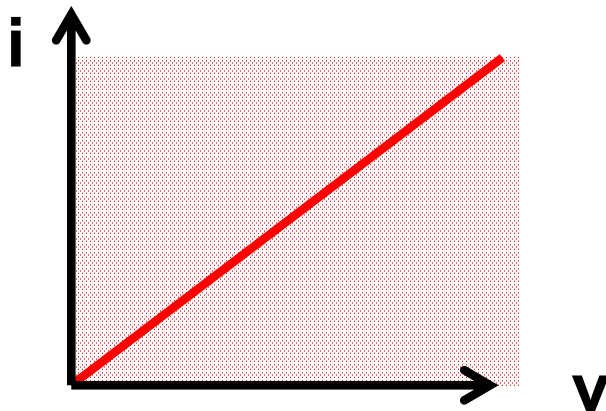
- Chapter 4 in the reader
- For more details look at
 - A&L 5.1 Digital Signals
 (goes in much more detail than we need)
 - A&L 6-6.3 MOS Devices

MOSFET a.k.a. MOS Transistor

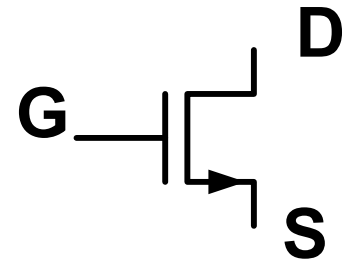
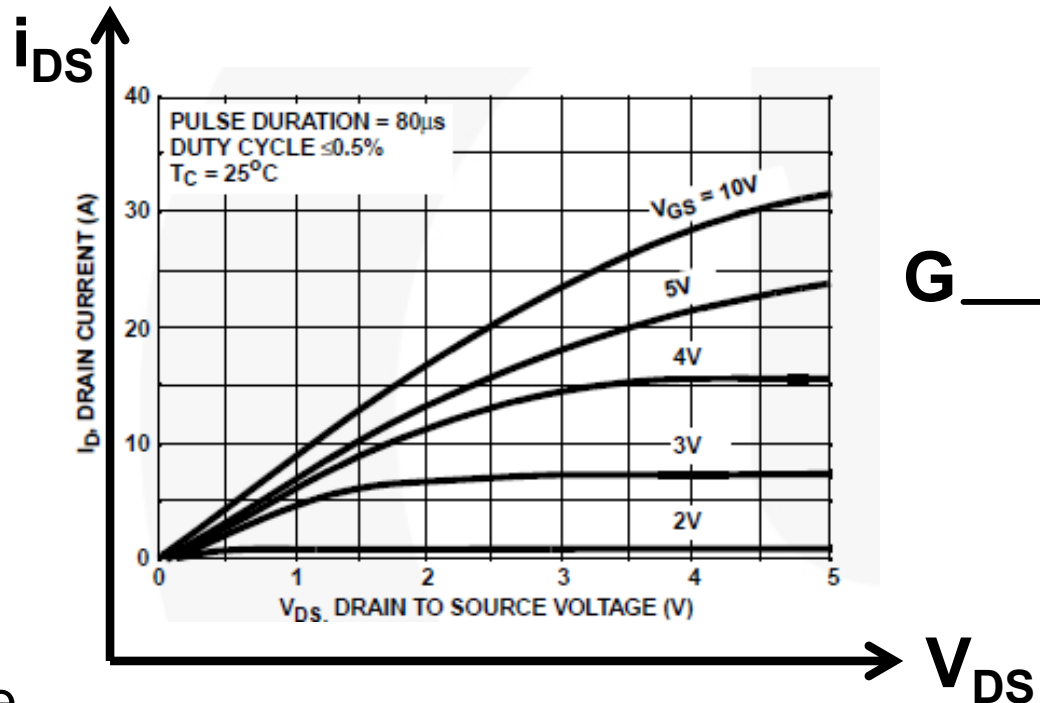
- Are very interesting devices
 - Come in two “flavors” – pMOS and nMOS
 - Symbols and equivalent circuits shown below
- Gate terminal takes no current (at least no DC current)
 - The gate voltage* controls whether the “switch” is ON or OFF



nMOS i-V Characteristics



Remember the resistor?



- nMOS is still a device
 - Defined by its relationship between current and voltage
 - But it has 3 terminals!
 - Current only flows between the source and drain
 - No current flows into the gate terminal!

Simple Model of an nMOS Device

- We will model an nMOS device by components we know

- Resistor
- Switch

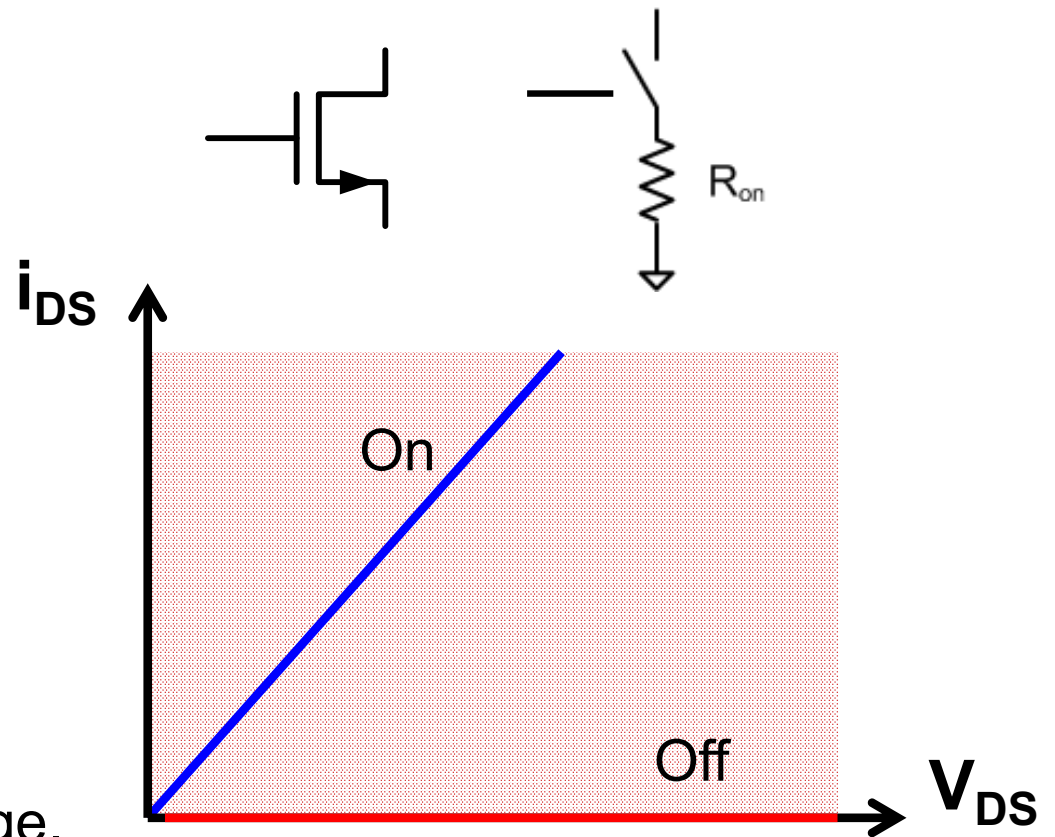
- NMOS

Source = Gnd

Gate = Gnd => Off

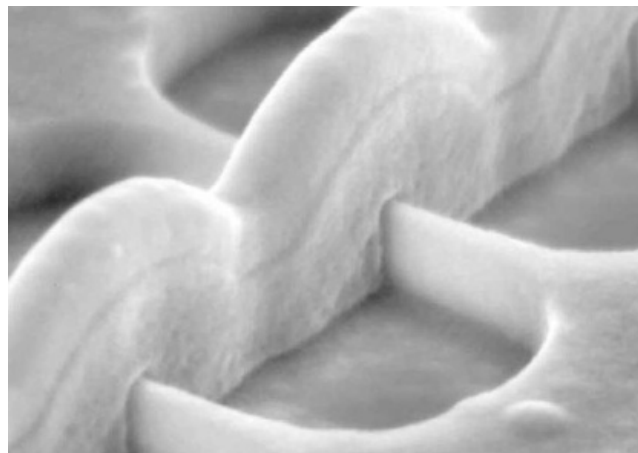
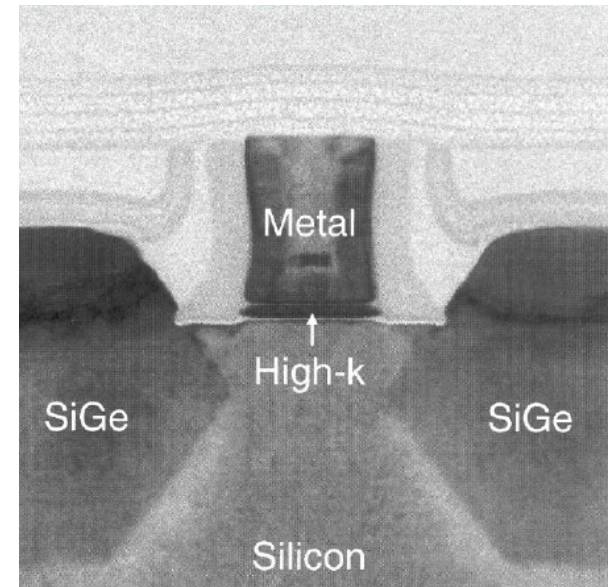
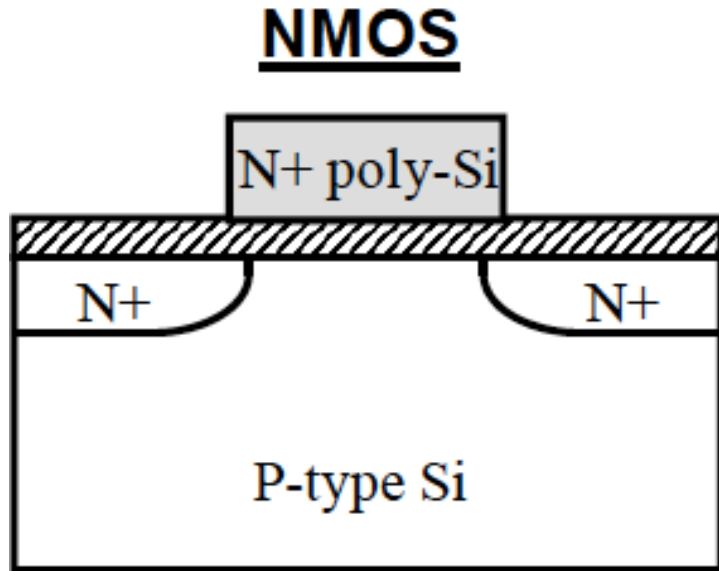
Gate = Vdd => On

- This really simple model is suitable for applications where there's one value of "On" voltage.



How Does an nMOS Transistor Actually Work?

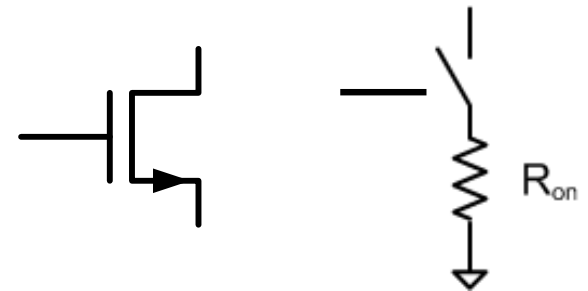
(FYI – not essential for this course)



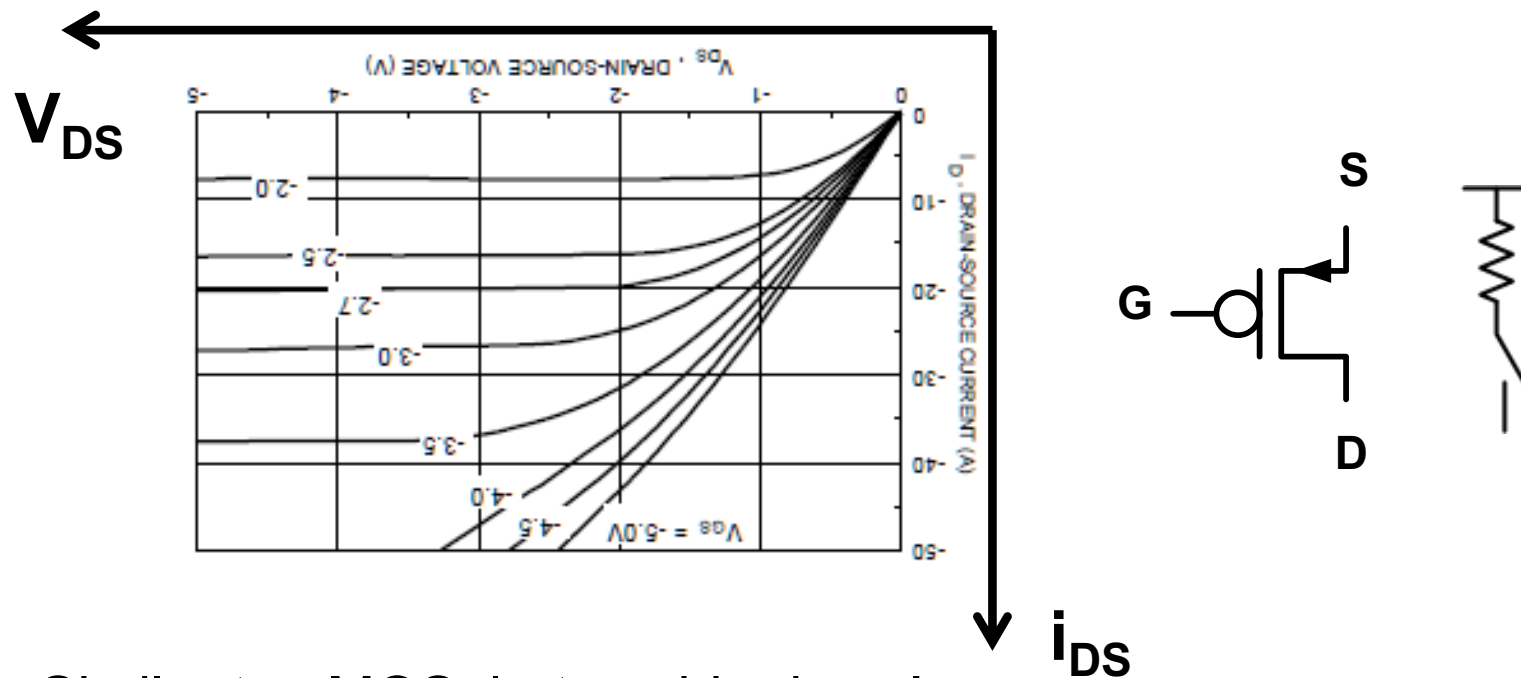
<http://www.extremetech.com/wp-content/uploads/2014/09/close+finfet.jpg>

Problem With nMOS Device

- While an nMOS device makes a great switch to Gnd
- It doesn't work that well if we want to connect to Vdd
 - To turn transistor on
 - Gate needs to be higher than source
 - But we want the source to be at Vdd
 - Oops ...



pMOS i_{DS} vs. V_{DS} Characteristics



- Similar to nMOS, but upside down!
 - Turns on when the gate-to-source voltage is < -1 V
 - And the drain-to-source voltage should be negative
 - Source should be the terminal with the higher voltage!

Simple Model of a pMOS Device

- We will model an pMOS device by components we know

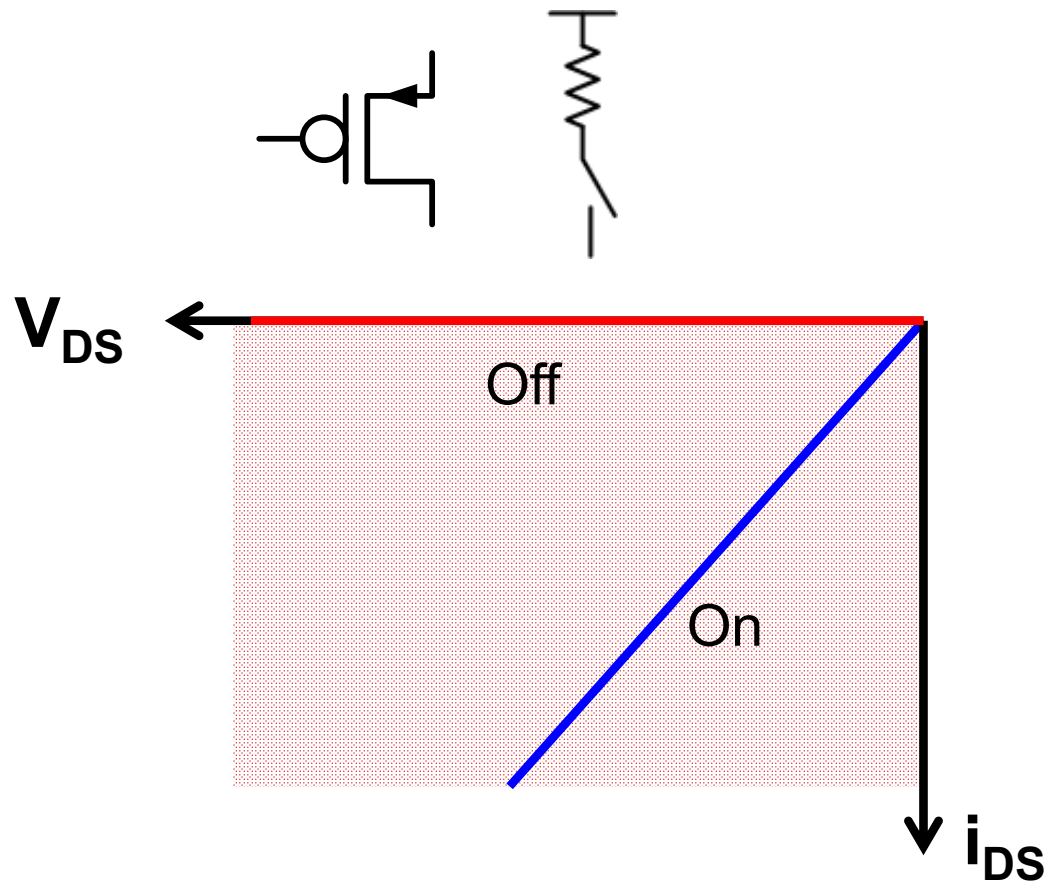
- Resistor
- Switch

- NMOS

Source = Vdd

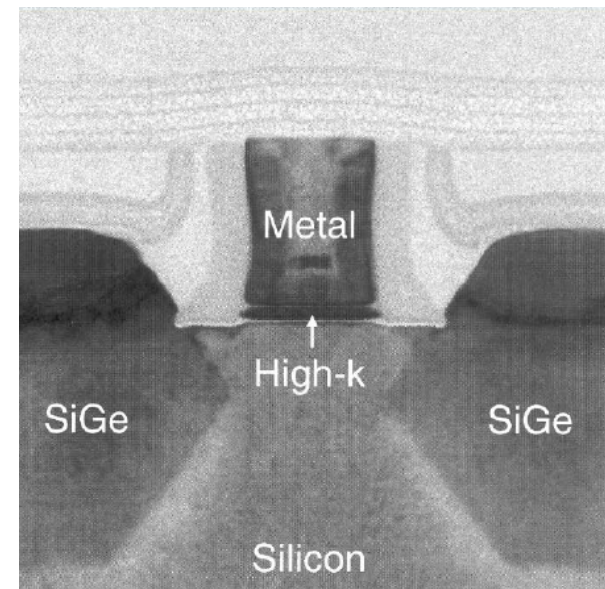
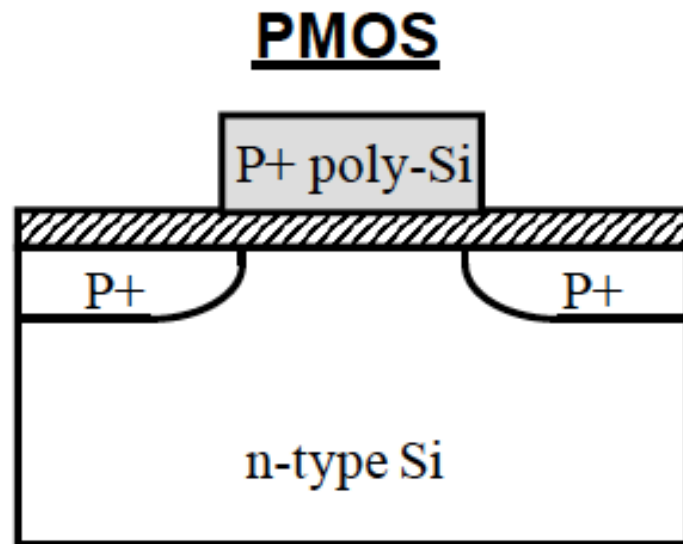
Gate = Gnd => On

Gate = Vdd => Off



How Does a pMOS Transistor Actually Work?

(FYI – not part of this course)



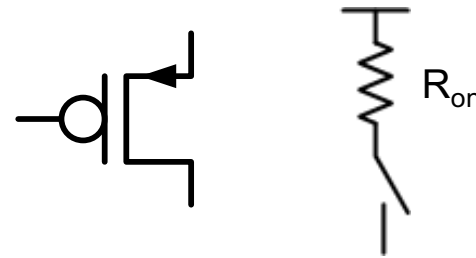
nMOS and pMOS Devices “Complement” Each Other – Complementary MOS or CMOS

- PMOS

Source = Vdd (+ supply)

Gate = Gnd => On

Gate = Vdd => Off

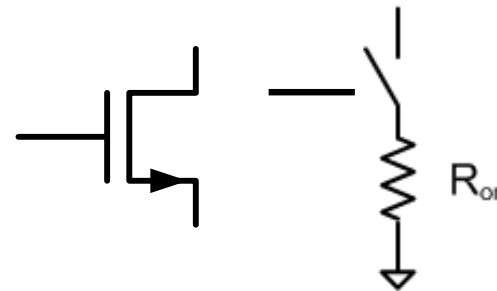


- NMOS

Source = Gnd

Gate = Gnd => Off

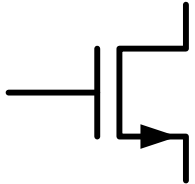
Gate = Vdd => On



MOS Transistor Summary

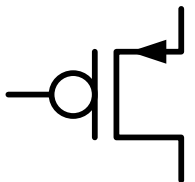
- MOS transistors are *extremely* useful devices
 - Almost all of your electronics uses them on the inside
 - Including your phone, laptop, WiFi and Bluetooth, and your Arduino
- Come in two “flavors”

- nMOS



- It is a switch which connects source to drain
 - If the gate-to-source voltage is greater than V_{th} (around 1 V)
 - Positive gate-to-source voltages turn the device on.

- pMOS



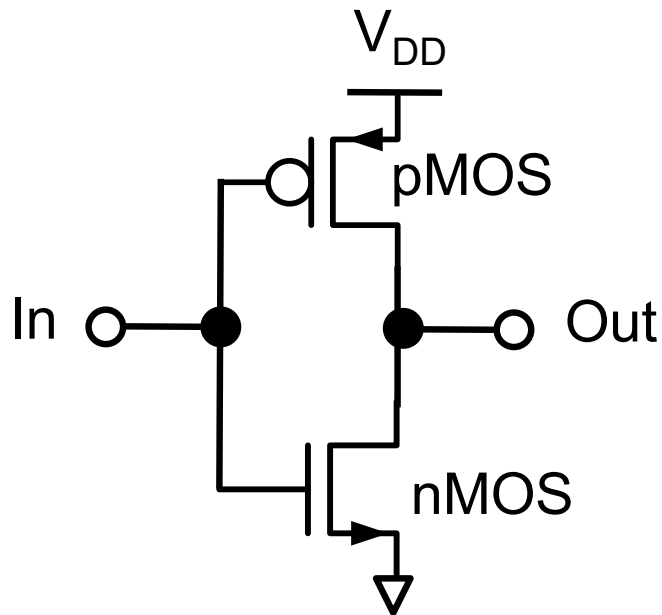
- It is a switch which connects source to drain
 - If the gate-to-source voltage is less than V_{th} (around -1 V)
 - Negative gate-to-source voltages turn the device on

... and there's zero current into the gate!

MOS Logic Gates

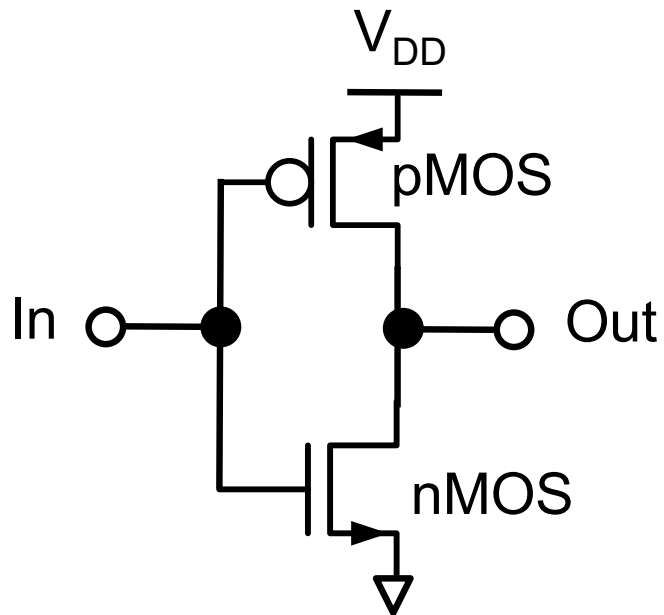
What Does This Circuit Do?

- Is the output a logic function of the input? Consider $V_{in} = \text{GND}$



What Does This Circuit Do?

- Now consider $V_{in} = V_{DD}$

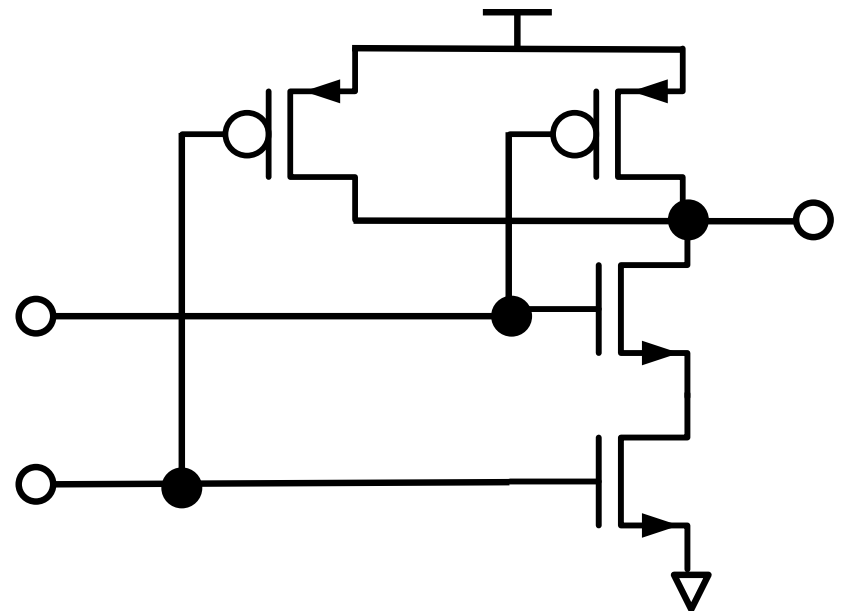


Building Logic Gates from MOS Transistors

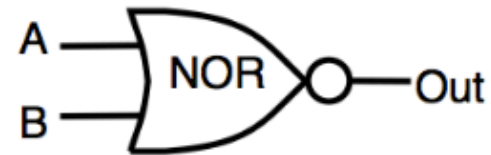
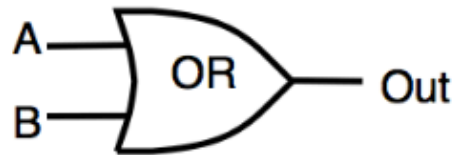
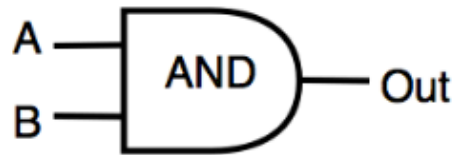
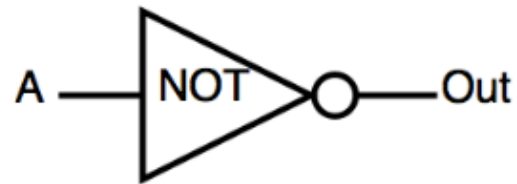
- Remember Boolean Logic?
 - AND, OR
 - NAND = Not-AND = AND followed by Inverter
 - Output is only low when A and B are true (high)
 - NOR = Not-OR = OR followed by Inverter
 - Output is low when either A or B is true (high)
- You can make them from MOS devices
 - But only the inverting gates (NOR and NAND)

Building a CMOS NAND Gate

- Output should be low if both input are high (true)
- Output should be high if either input is low (false)

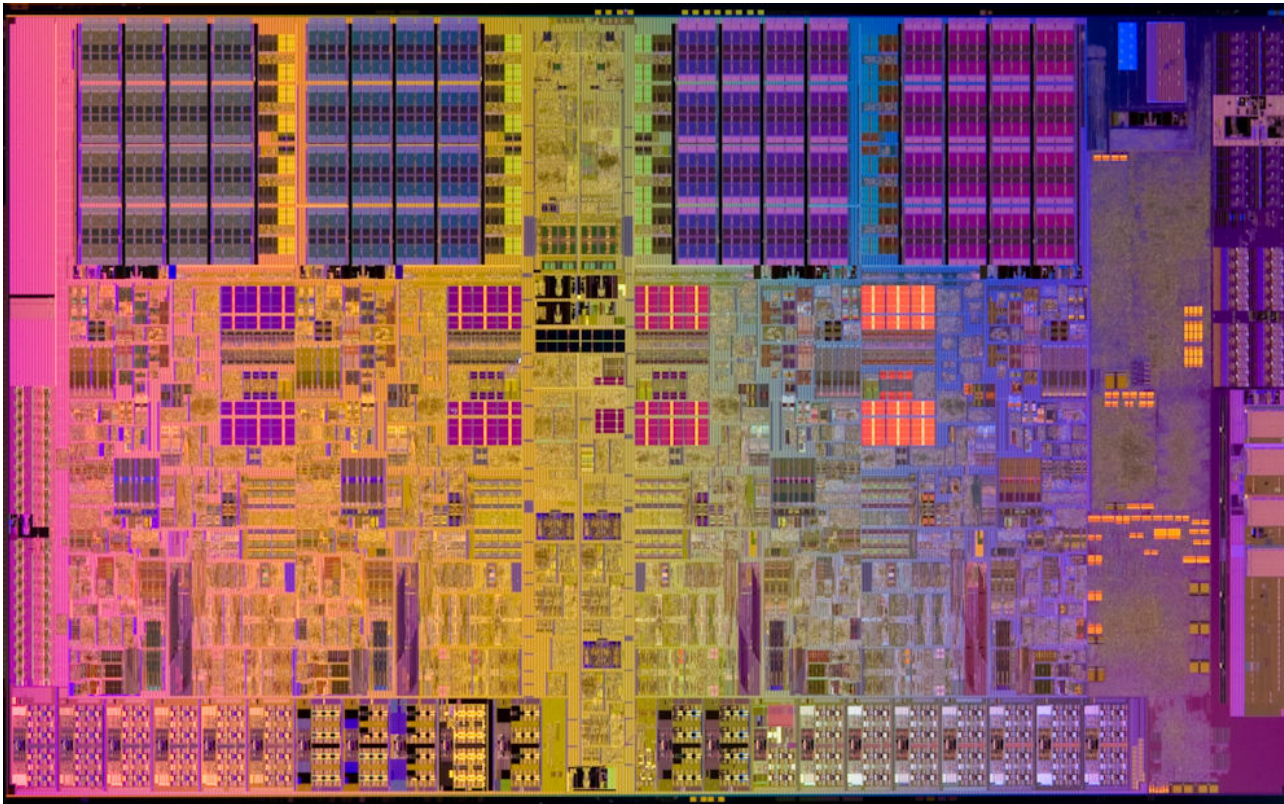


Logic Symbols



If You Look At Your Computer Chip

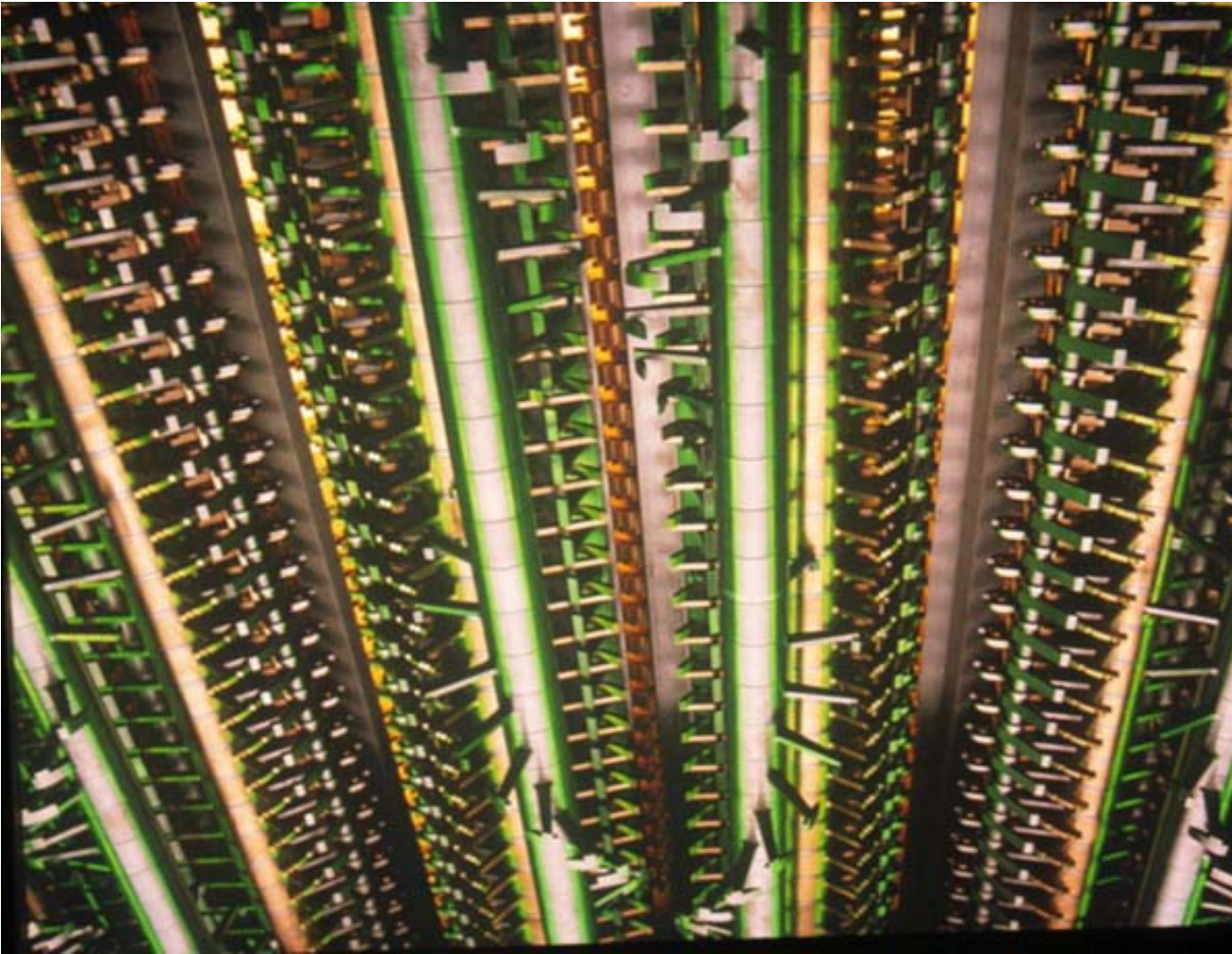
- It is just billions of transistors
 - Creating many logic gates, and memory



- Take EE108A if you want know how we do that ...

HOW THE MOS TRANSISTOR CHANGED THE WORLD ...

First Computing Machines Were Mechanical



Picture of a version of the Babbage difference engine built by the Museum of Science, UK

“The calculating section of Difference Engine No. 2, has 4,000 moving parts (excluding the printing mechanism) and weighs 2.6 tons. It is seven feet high, eleven feet long and eighteen inches in depth”

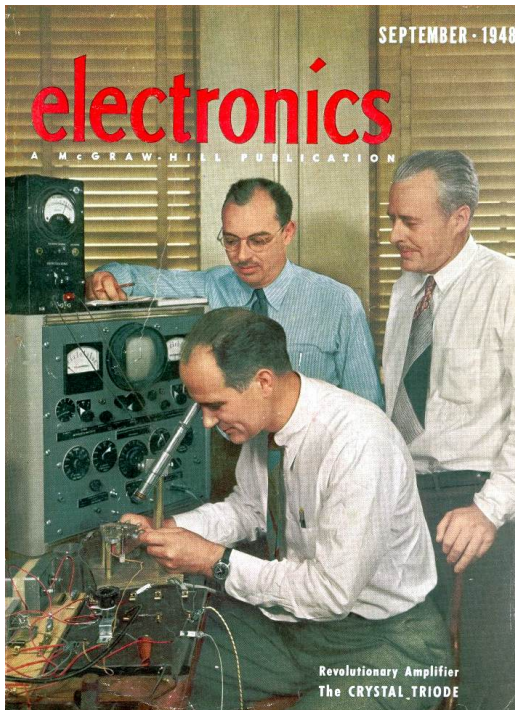
Moving Electrons is Easier than Moving Metal

- Building electronics:
 - Started with tubes, then miniature tubes
 - Transistors, then miniature transistors
 - Components were getting cheaper, more reliable but:
 - There is a minimum cost of a component (storage, handling ...)
 - Total system cost was proportional to complexity
- Integrated circuits changed that
 - Printed a circuit, like you print a picture,
 - Create components in parallel
 - Cost no longer depended on # of devices

A Little History

1st (Bipolar Junction) Transistor
Christmas Eve 1947

By Bardeen, Brattain, and Shockley,
Nobel Laureates in Physics 1956



(http://www.bellsystemmemorial.com/belllabs_transistor.html)



1st Integrated Circuit

Jack Kilby, Nobel Laureate in Physics
2000
Bob Noyce



1958



(Courtesy of TI and Huff, SEMATECH)

What is an Integrated Circuit?

- A device having multiple electrical components and their interconnects manufactured on a single substrate.
- First IC 1958
 - Jack Kilby at TI
 - Germanium
 - A hack
 - Wax support
 - Made history
- Planar Process 1961
 - Bob Noyce at Fairchild
 - Silicon

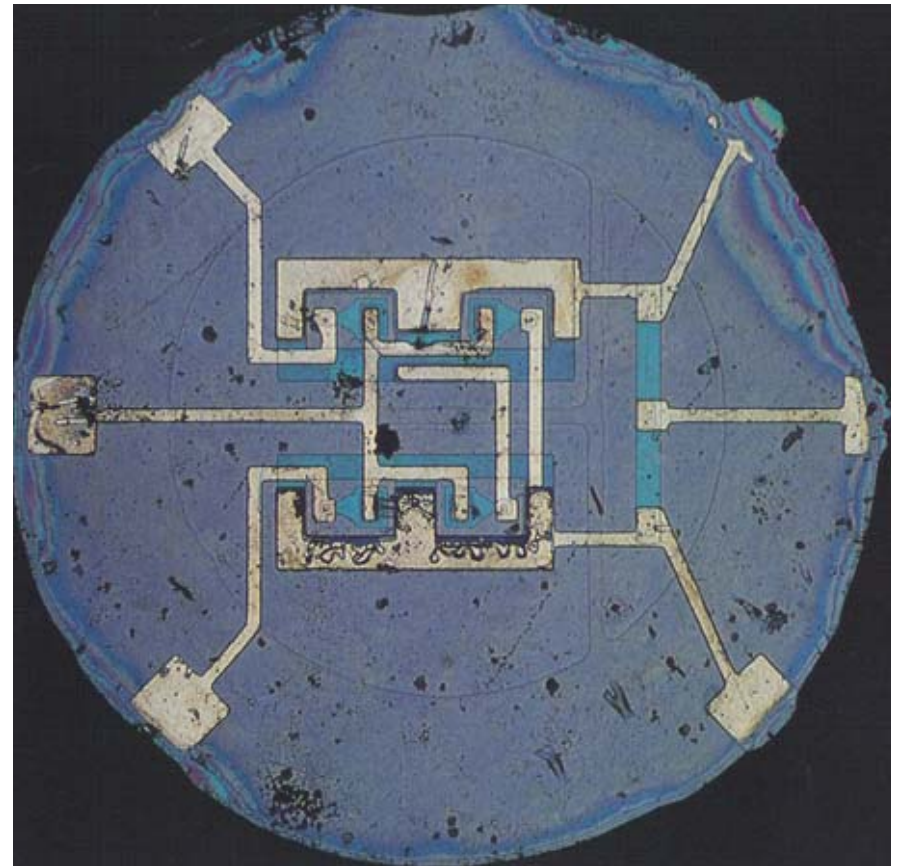
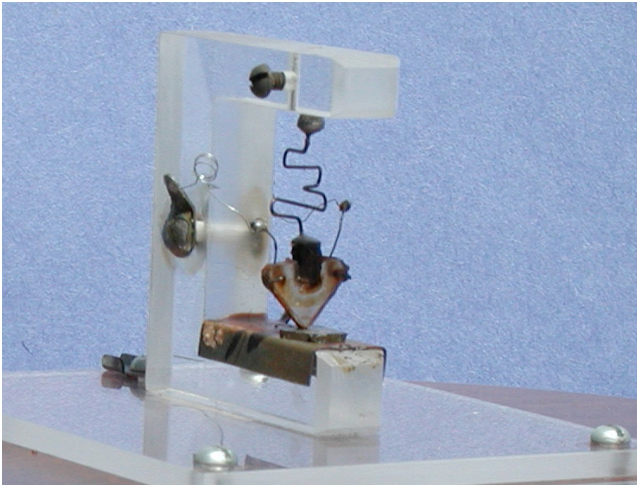


Image from State of the Art © Stan Augarten

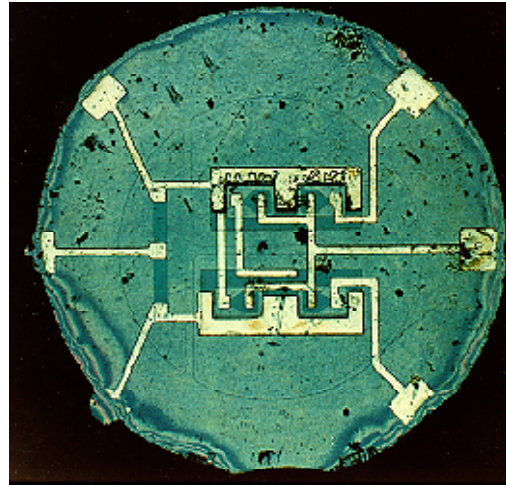
Miniaturization Progress Over 50 Years

From This



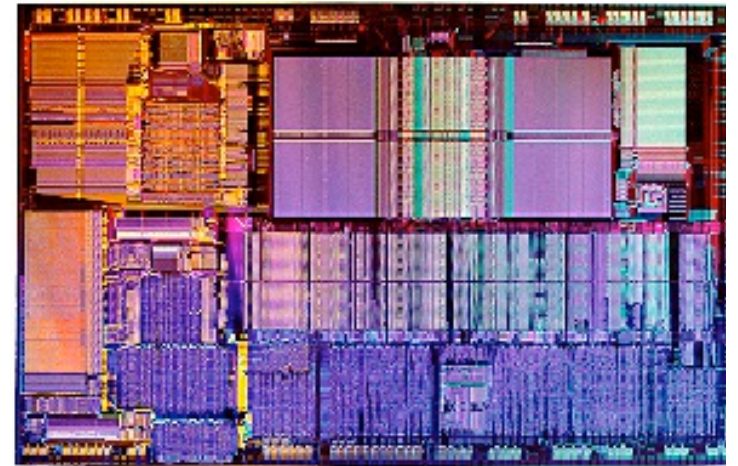
Point Contact Transistor

To This



First Integrated Circuit

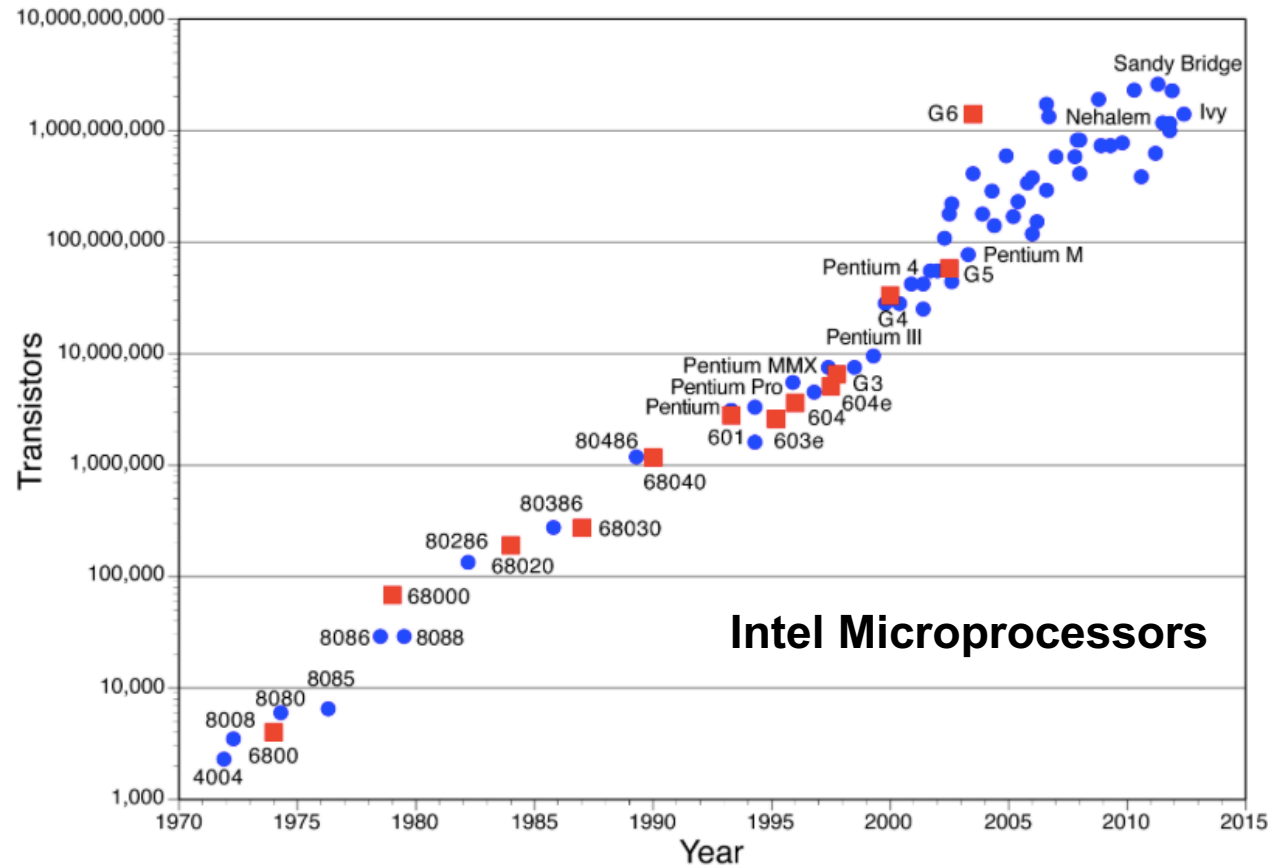
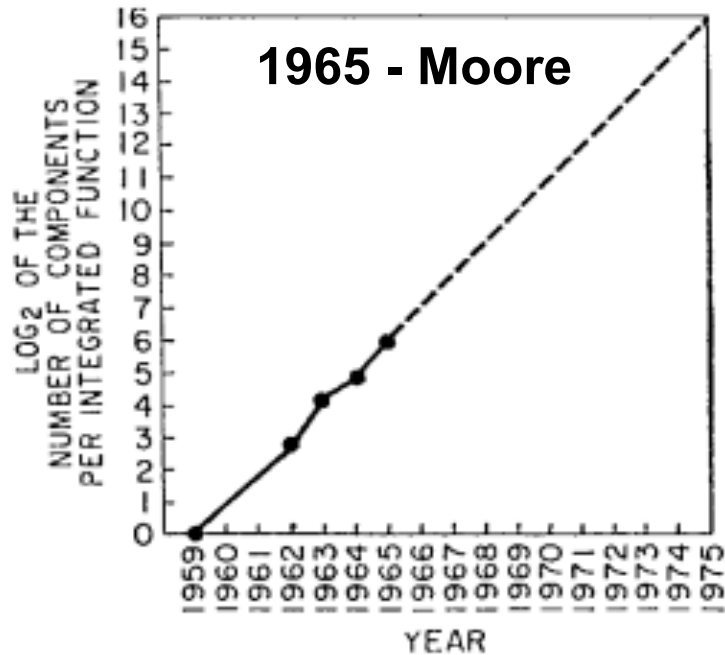
To This



Modern Microprocessor

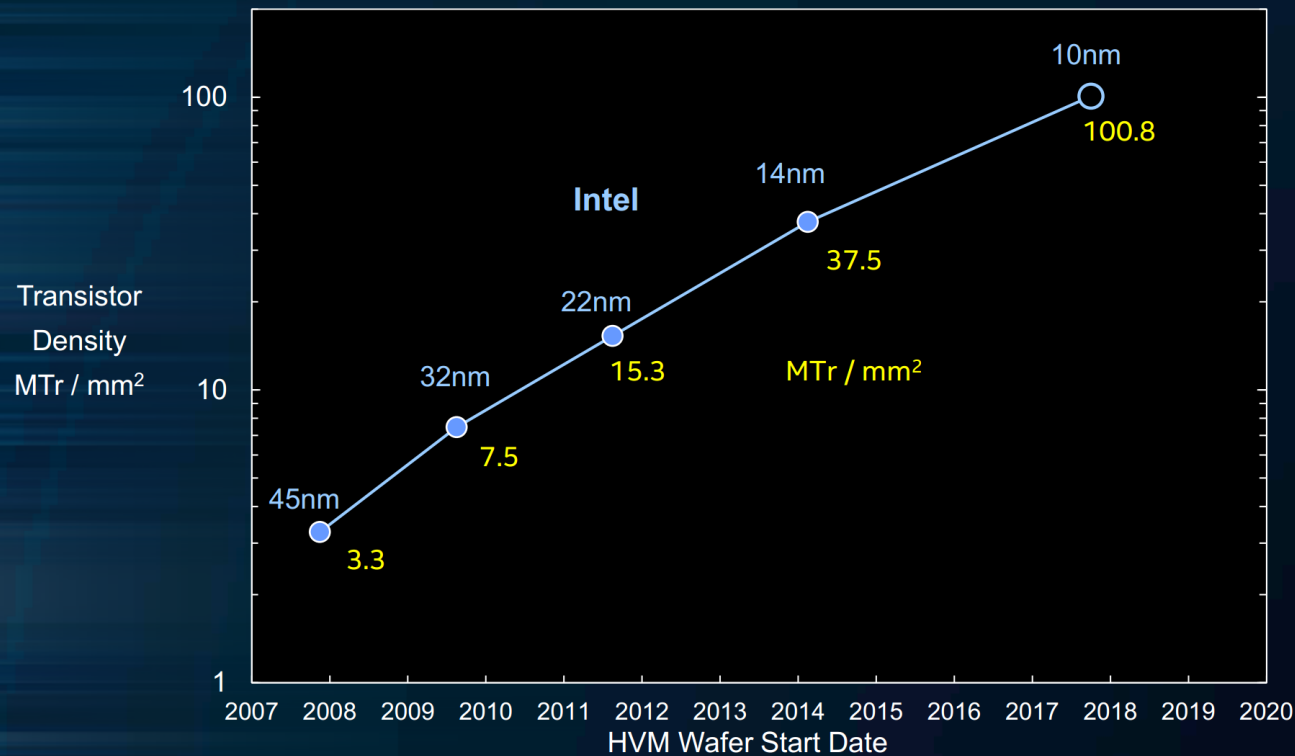
- Modern silicon chips have $> 10^9$ components in 1 cm^2 area.

Moore's "Law"



- “The complexity for minimum component costs has increased at a rate of roughly a factor of 2 per year.” Gordon Moore, 1965

LOGIC TRANSISTOR DENSITY



Intel 10 nm hyper scaling features result in Transistor Density above 100MTr/mm²

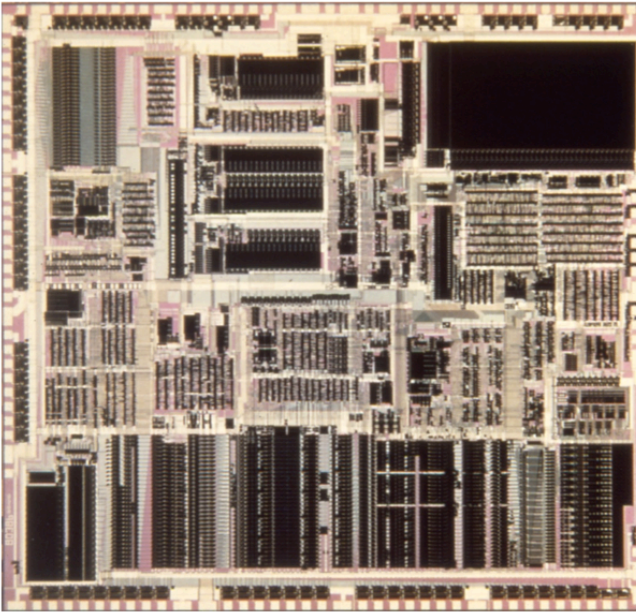
TECHNOLOGY AND MANUFACTURING DAY

Source: Intel. 2017-2020 are estimates based upon current expectations and available information.



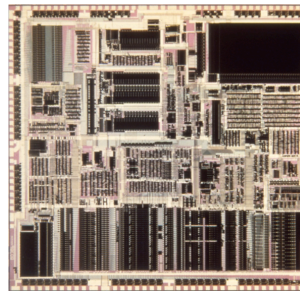
Kaizad Mistry, Intel Technology and Manufacturing Day, March 28, 2017

What This Means



1985 (Intel 80386)
275,000 transistors
104 mm²; 2640 Tr/mm²

80386 chip area
shrinks to 17 mm²



1989 (Intel 80486)
1,180,235 transistors
16,170 Tr/mm²

80386 die size
shrinks to 0.05 mm²



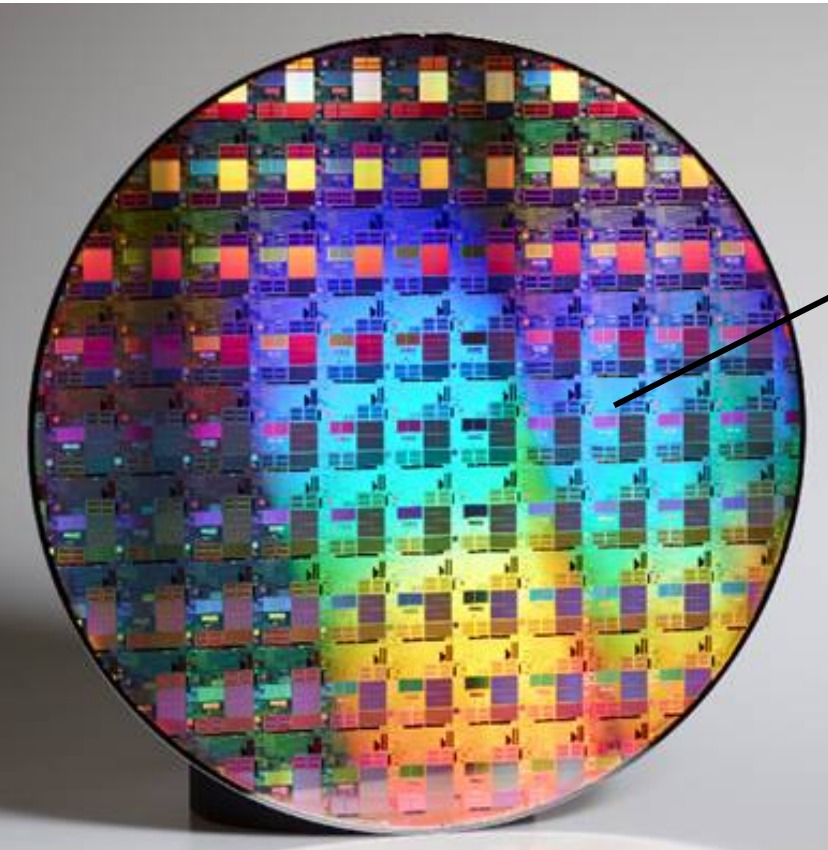
Chip edge is only twice the
diameter of a human hair!

Intel 10 nm CMOS*
circa 2019
100,000,000 Tr/mm²

... or the original chip area could contain > 10 billion transistors!

*Kaizad Mistry, Intel Technology and Manufacturing Day, March 28, 2017

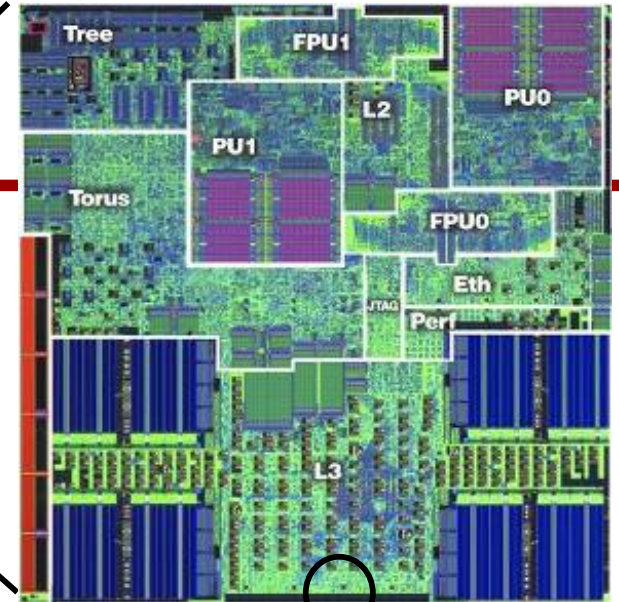
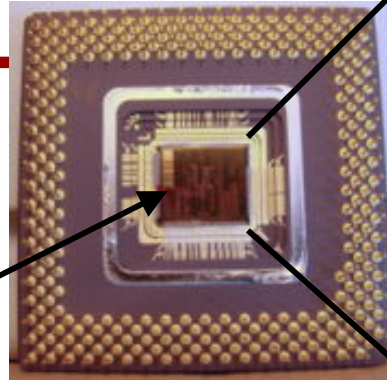
Take The Cover Off A Microprocessor



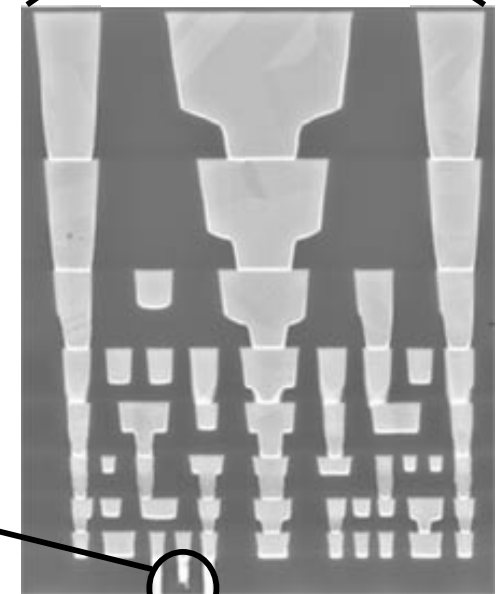
Full wafer (100s of dies)

modern wafers: 200-300 mm
diameter (8-12 inches)

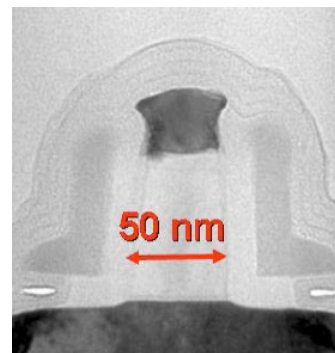
Packaged die



Cross-section



Single transistor



Learning Objectives

- Understand how nMOS and pMOS transistor work
 - Voltage controlled switch, the gate voltage controls whether the switch is ON or OFF
 - nMOS devices connect output to Gnd
 - pMOS devices connect the output to Vdd
- Be able to create MOS NAND, NOR and Inverter circuits
 - Using pMOS and nMOS devices